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на гл. ас. д-р Ирина Бинева

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От тях:

- 1 признат български патент (№31),
- 1 автореферат на дисертация (№32),
- 3 глави от книги (№ 4, 10, 30),
- 18 публикации в международни списания с импакт фактор(IF)/импакт ранк (SJR) - № 5-7, 12-16, 18, 19, 21-24, 26-29).

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